



~~Att~~y. Docket No. 4192.P053D2

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

~~§ 87(2)(b)~~ re Application of:

Min-hwa Chin

Application No.: 10/642,416

Filed: August 15, 2003

For: TRANSISTOR AND LOGIC CIRCUIT ON THIN)
SILICON-ON-INSULATOR WAFERS BASED ON)
GATE INDUCED DRAIN LEAKAGE CURRENTS)

) Examiner: Not yet assigned

) Art Unit: Not yet assigned

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

REQUEST FOR STATUS OF APPLICATION

Dear Commissioner:

Please inform us on the current status of the above-referenced patent application.

If there are any further charges, please charge them to Deposit Account No. 02-2666.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

Dated: 5/31/2005

Jan Little-Washington
Reg. No. 41,181

12400 Wilshire Blvd.
Seventh Floor
Los Angeles, CA 90025-1026
(206) 292-8600

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I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage in an envelope addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on

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